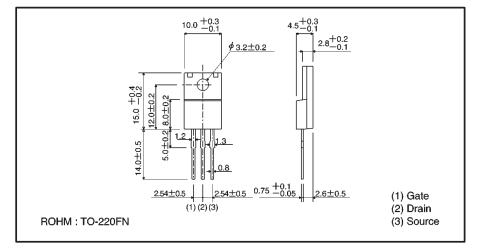
# Transistors

# Switching (450V, 5A) 25K2713

## Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Wide SOA (safe operating area).
- Gate-source voltage (V<sub>GSS</sub>) guaranteed to be ±30V.
- 5) Easily designed drive circuits.
- 6) Easy to parallel.

Structure
 Silicon N-channel
 MOSFET



External dimensions (Units: mm)

## •Absolute maximum ratings (Ta = $25^{\circ}$ C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		Voss	450	V
Gate-source voltage		Vgss	±30	V
Drain current	Continuous	lo	5	А
	Pulsed	ldp*	20	А
Reverse drain	Continuous	<b>I</b> DR	5	А
current	Pulsed	Idrp*	20	А
Total power dissipation (Tc=25°C)		Po	30	W
Channel temperature		Tch	150	°C
Storage temperature		Tstg	-55~+150	°C

\*  $Pw \leq 10 \ \mu s$ , Duty cycle  $\leq 1\%$ 

#### Packaging specifications

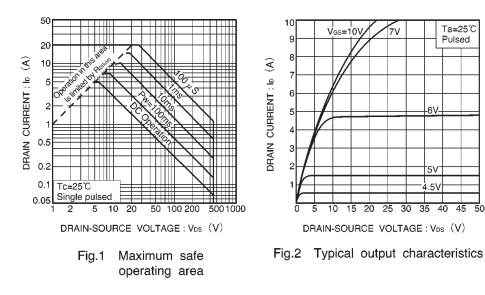
	Package	Bulk
Туре	Code	
	Basic ordering unit (pieces)	500
2SK2713		0

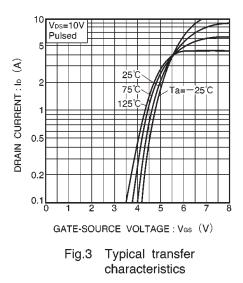


## •Electrical characteristics (Ta = $25^{\circ}$ C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Conditions
Gate-source leakage	lass			±100	nA	$V_{GS}=\pm 30V, V_{DS}=0V$
Drain-source breakdown voltage	V(BR)DSS	450	_	_	V	ID=1mA, VGS=0V
Zero gate voltage drain current	loss	_	_	100	μA	V <sub>DS</sub> =450V, V <sub>GS</sub> =0V
Gate threshold voltage	VGS(th)	2.0		4.0	V	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA
Static drain-source on-state resistance	RDS(on)		1.0	1.4	Ω	ID=2.5A, VGS=10V
Forward transfer admittance	Y <sub>fs</sub>	1.0	3.0	_	S	ID=2.5A, VDS=10V
Input capacitance	Ciss	_	600	_	pF	V <sub>DS</sub> =10V
Output capacitance	Coss	_	135	_	рF	V <sub>GS</sub> =0V
Reverse transfer capacitance	Crss		53	_	pF	f=1MHz
Turn-on delay time	td(on)		14	_	ns	I□=2.5A, V□□≑150V
Rise time	tr		17	_	ns	V <sub>GS</sub> =10V
Turn-off delay time	td(off)	_	50	_	ns	$RL = 60 \Omega$
Fall time	tr	_	35	_	ns	$R_G=10\Omega$
Reverse recovery time	trr		300	_	ns	IDR=5A, VGS=0V
Reverse recovery charge	Qrr		1.8	_	μC	di/dt=100A/ μs

Electrical characteristic curves





ROHM

Ta=25℃

Pulsed

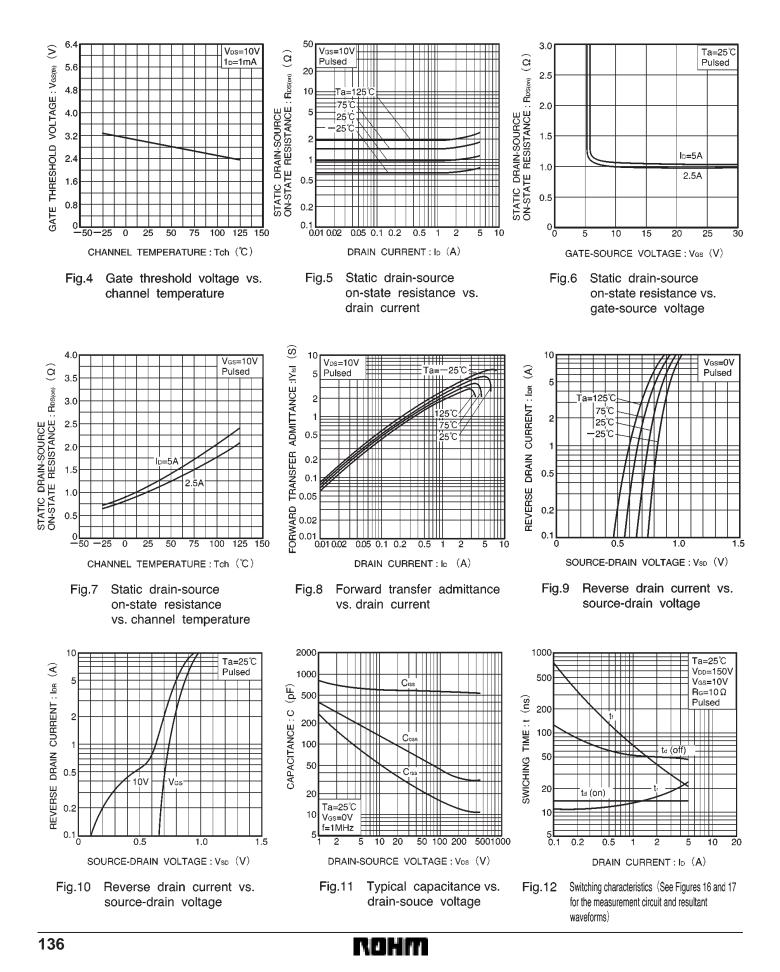
5V

.5V

45 50

7V

# Transistors



# **Transistors**

-O V⊳s

Śr⊾

Vdd

⊃ V⊳s

ŚR∟

VDD

Ь

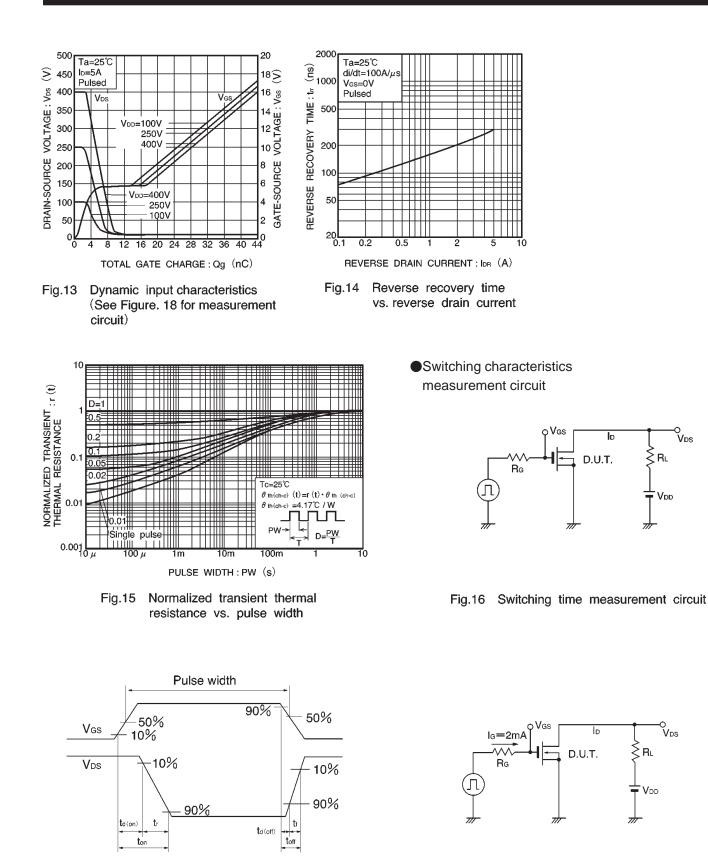


Fig.18 Gate charge measurement circuit

ROHM

Fig.17 Switching time waveforms

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